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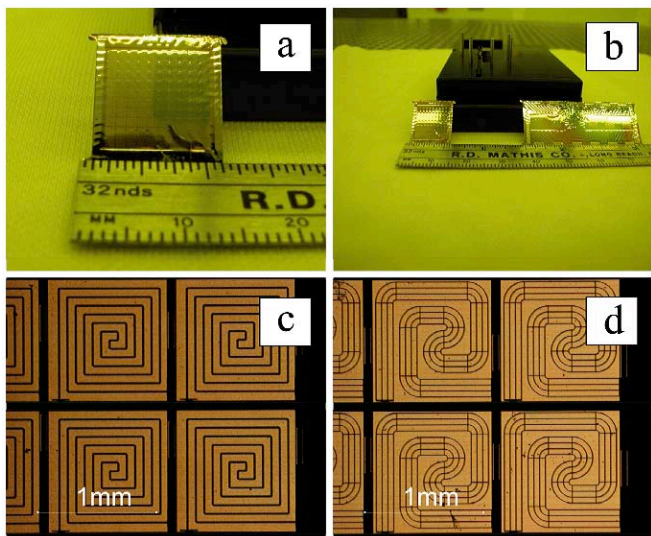
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# Integrated Optics for Submillimeter Spectroscopy: Introducing $\mu$ -Spec

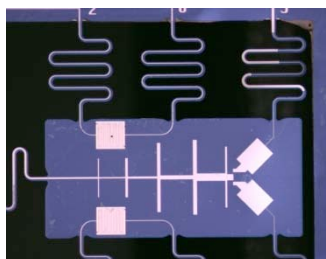
Harvey Moseley

Dominic Benford, Matt Bradford, Ari Brown,  
Kevin Denis, Negar Ehsan, Wei-Chung  
Huang, Wen-Ting Hsieh, Thomas  
Stevenson, Kongpop U-yen, Edward J.  
Wollack, and Jonas Zmuidzinas

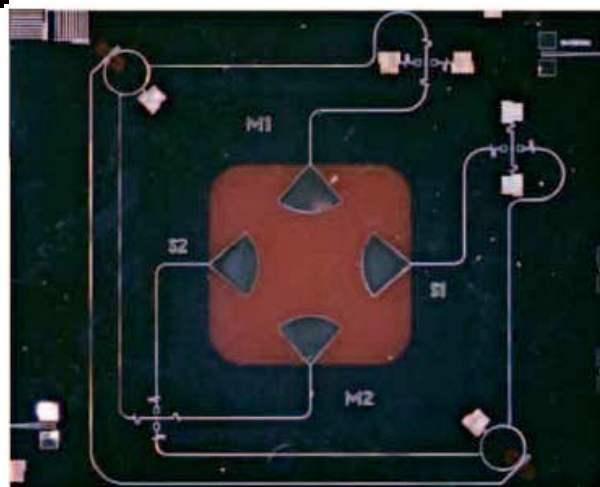
# Goddard Microwave Design Capabilities



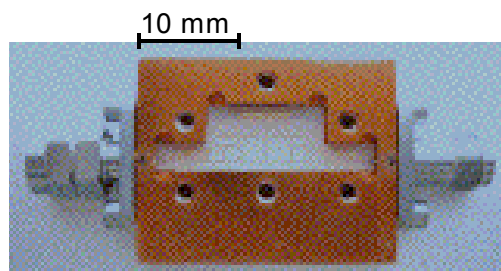
Microwave Kinetic Inductance Detector with Selective Polarization Coupling



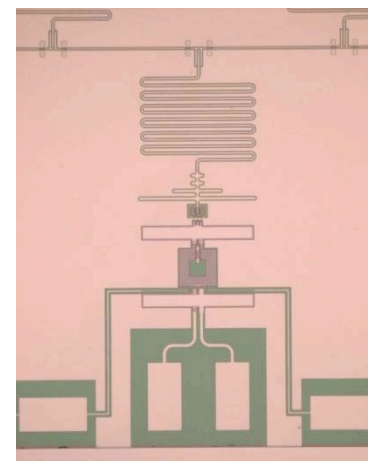
Broadband TES Termination



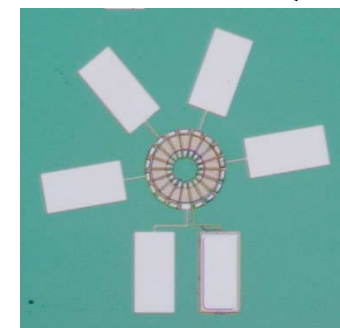
CMBpol Detector



Thermal Blocking Filter



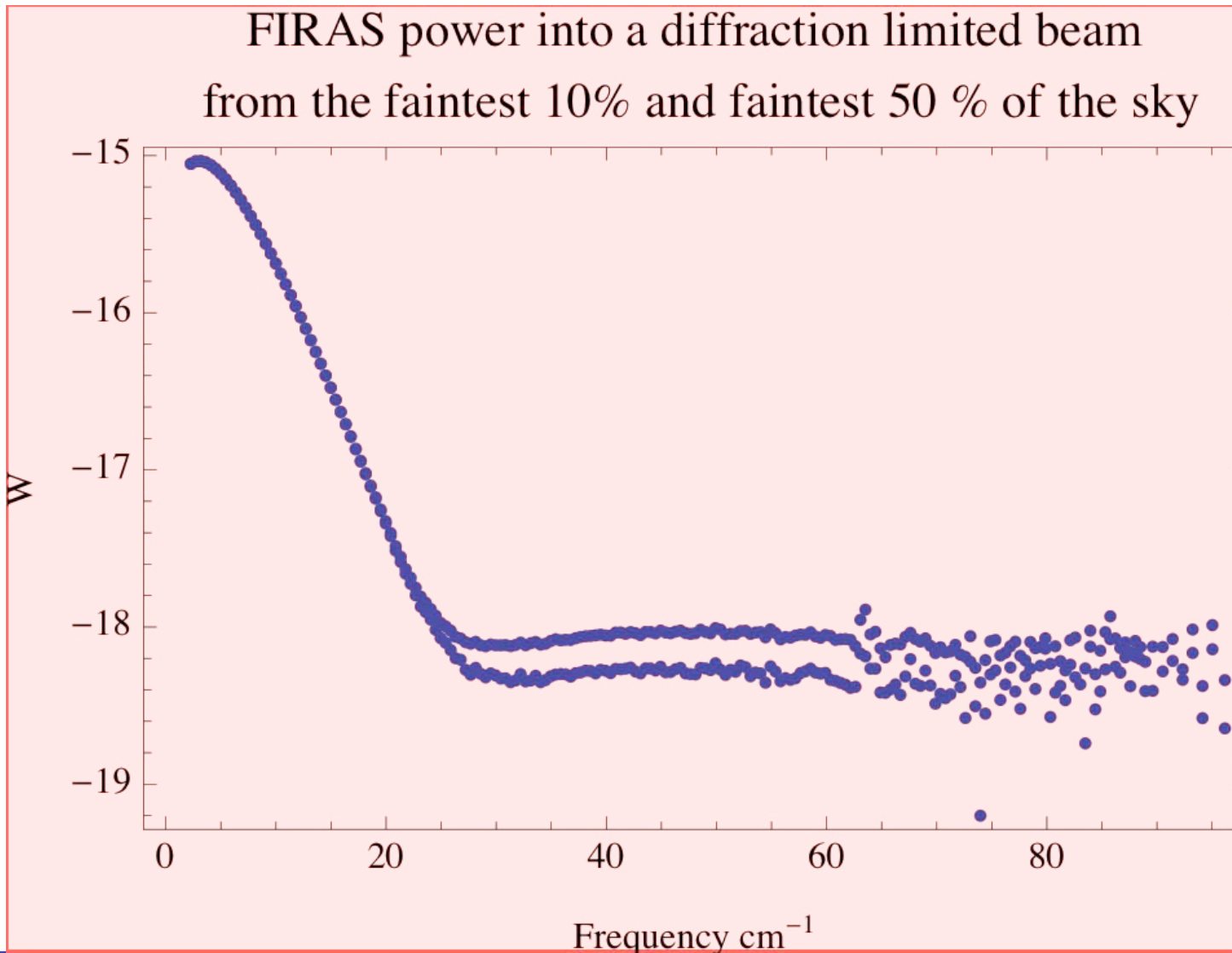
Microwave SQUID



Planar Transformer with high  $\mu$  material



# The Space Environment

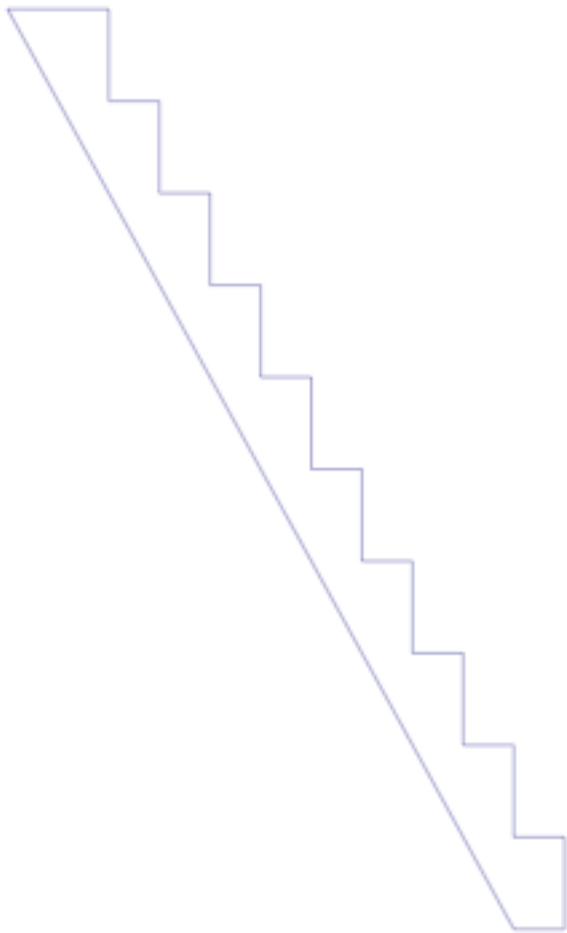




# Grating Operation

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Plane wave scatters off grating

Grating divides amplitude into  $n$  equal parts with progressively increasing phase shift

Different Frequencies propagate as plane waves with different  $k$ -vectors



# Grating Spectrographs

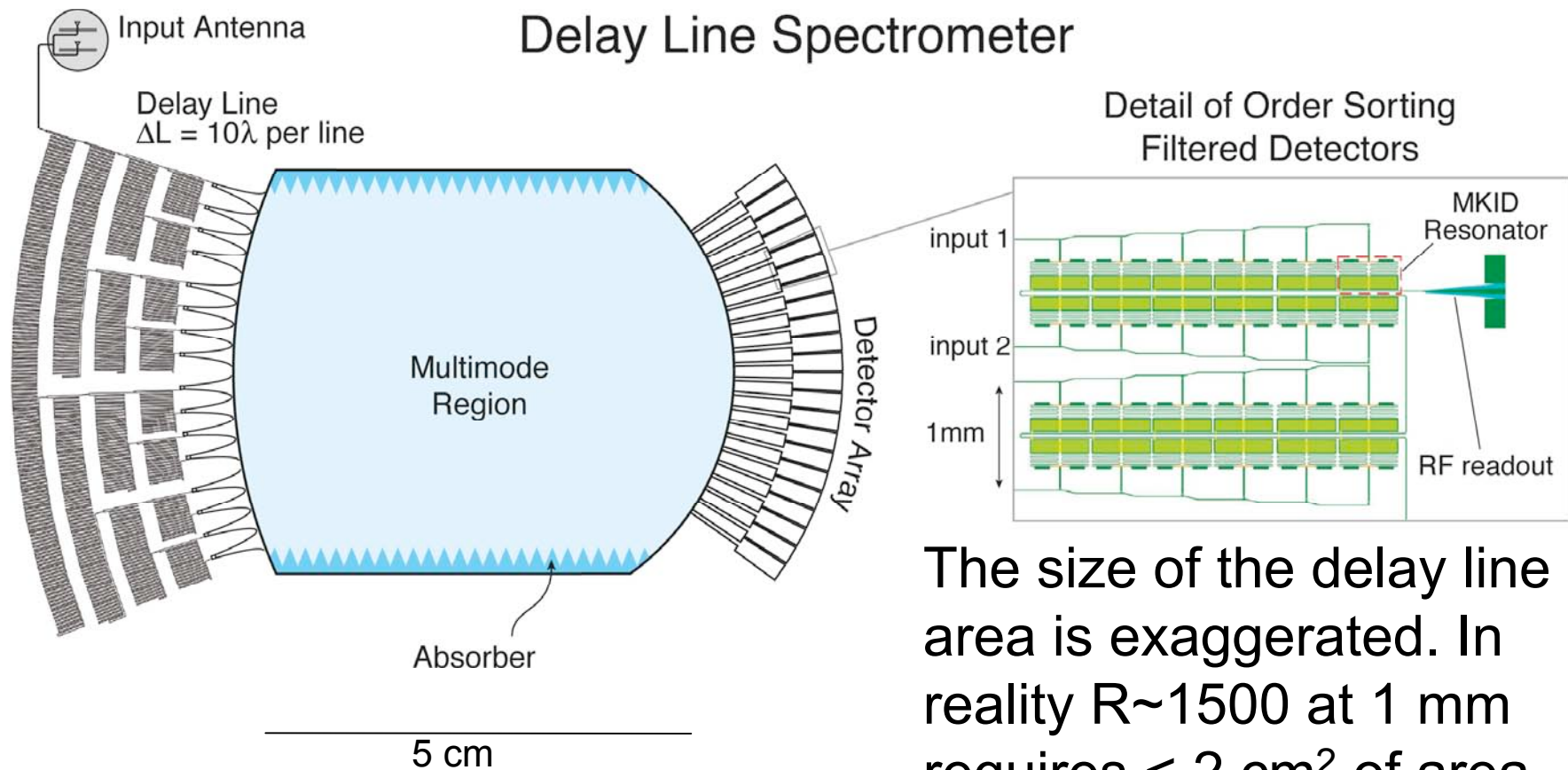
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- Resolving power is set by total phase delay, which is of the order of the size of the instrument. Must be large for high resolution.
- Focal surface must have of order  $N$  detectors for full sampling of an octave at resolving power  $N$ . Since detectors must be of order  $\lambda$  in size, the transverse dimension must be large, similar to the length
- So: Spectrograph must be of order  $N \lambda \times N \lambda$



# $\mu$ -Spec Allows Dramatic Reduction in Spectrograph Size

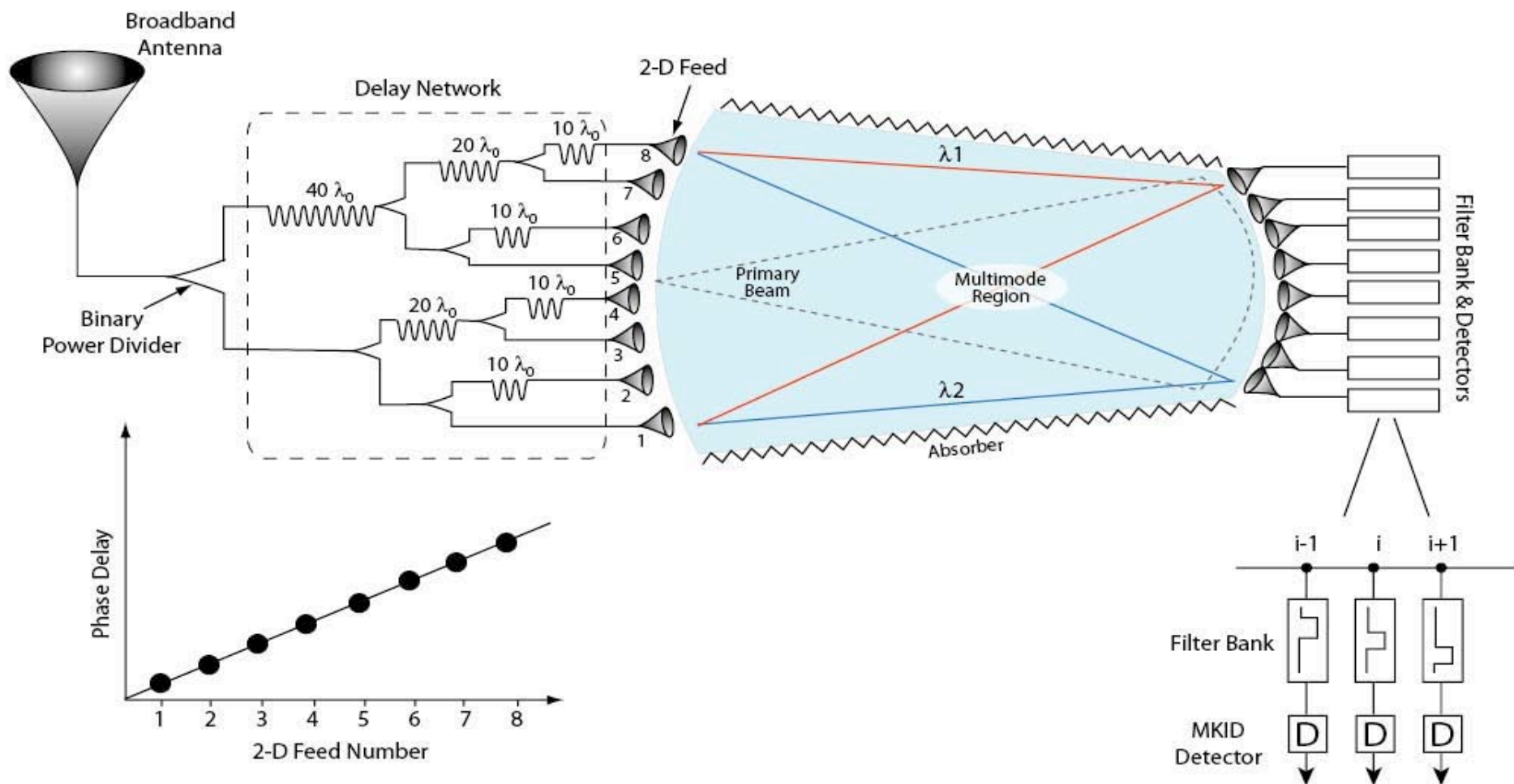


The size of the delay line area is exaggerated. In reality  $R \sim 1500$  at 1 mm requires  $< 2 \text{ cm}^2$  of area.

Key Technology – low loss transmission lines  
Superconductors with single crystal Si dielectric  
Bulk loss of Si is low enough



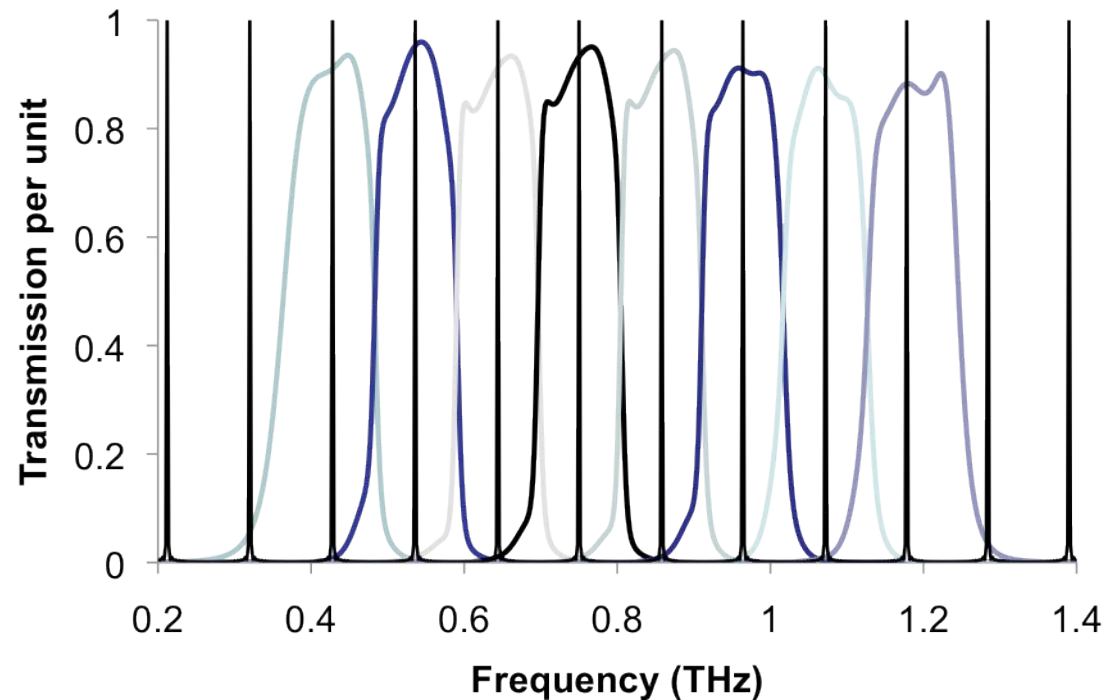
# $\mu$ -Spec Concept





# Output Filter Bank

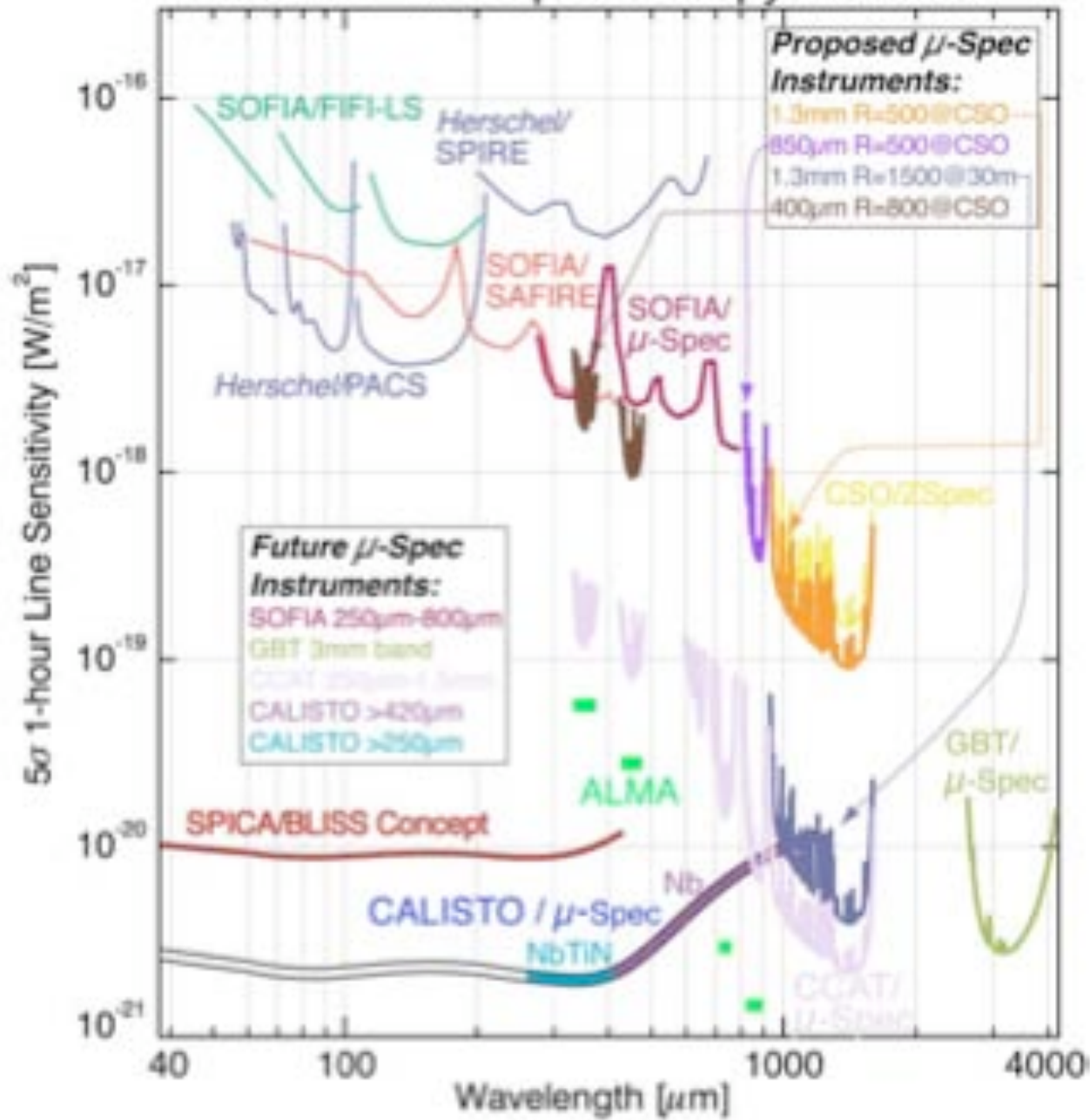
- Each output of the spectrometer receives signals at different wavelengths from different orders of the grating
- Each output has a channelizing filter bank which directs the different orders to their detectors.





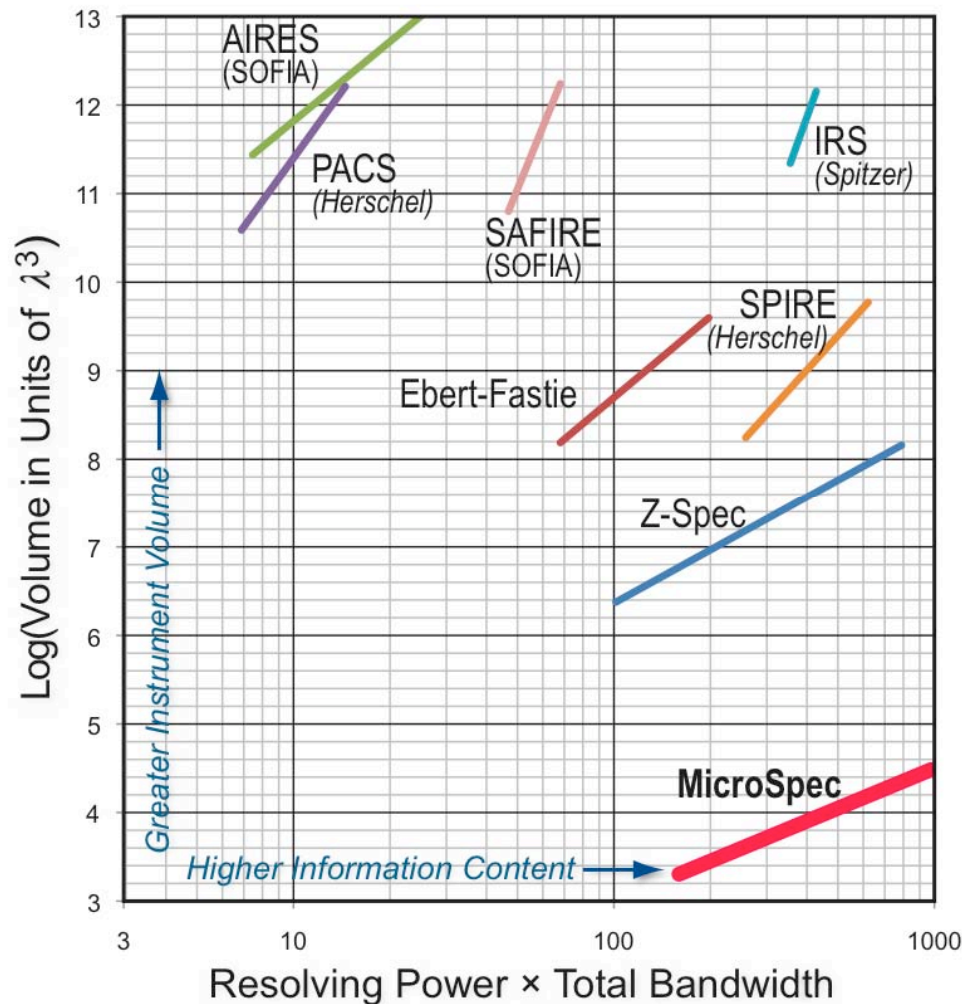


# Submm – mm Spectroscopy Platforms





# Context

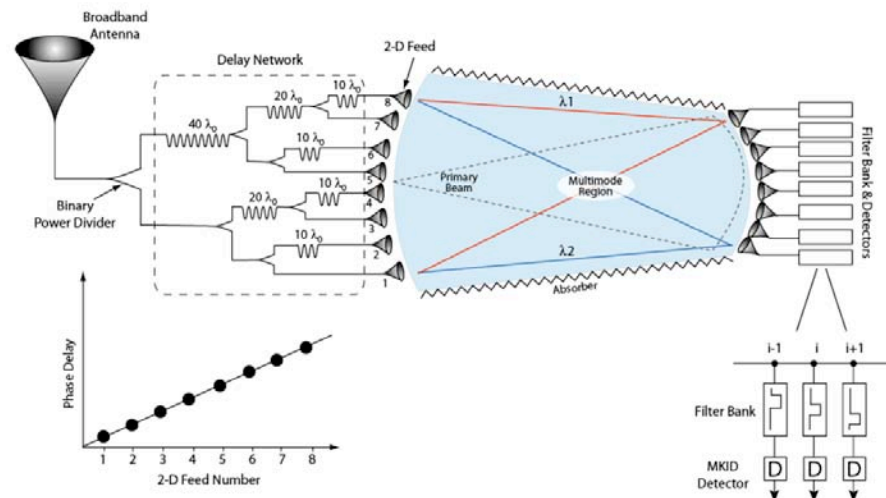


MicroSpec ( $\mu$ -Spec), the instrument being proposed, is orders of magnitude smaller than present instruments of comparable performance.

Adapted from a Matt Bradford slide.

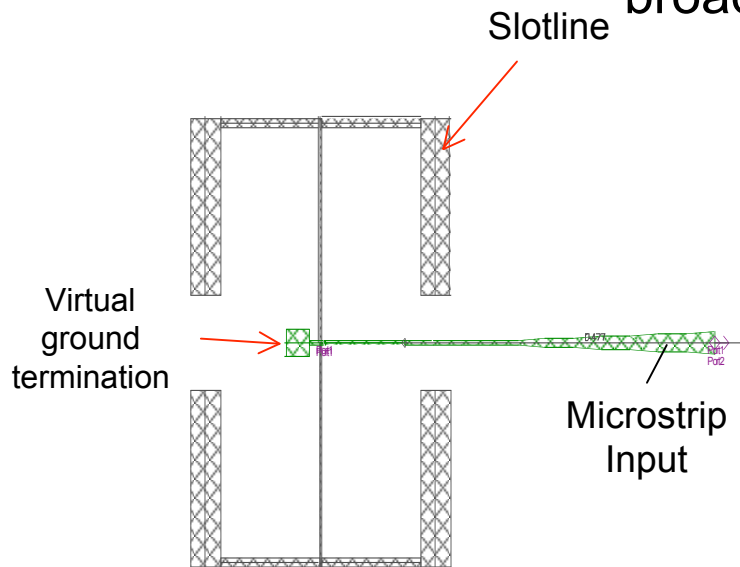
# Microwave Technology Implementations

- Ultra-broadband antenna
- Front-back microstrip transition
- Channelizing filter
- Plane-wave absorber
- Low Noise Equivalent Power (NEP) Microwave Kinetic Inductance Detector (MKID)



# Ultra-broadband Slot Antenna

New slotline antenna design use slotline-to-microstrip transition & slotline impedance transformation concept to generate an ultra-broadband antenna



Return loss (dB)

0

-10

-20

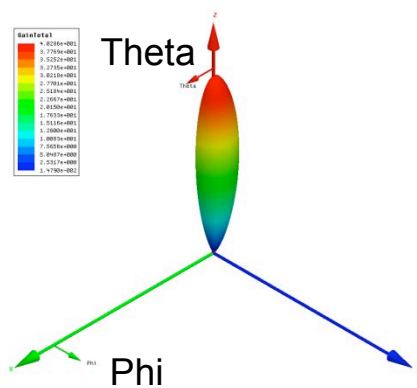
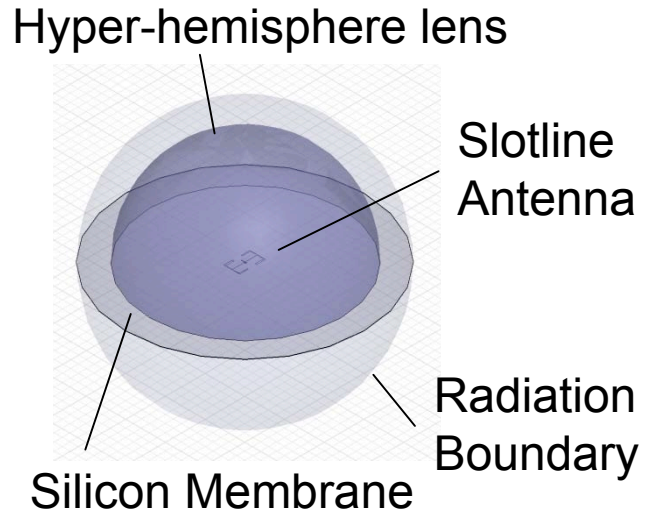
-30

Slotline Antenna  
on 1.5  $\mu\text{m}$  Silicon  
Substrate

200 300 400 500 600 700  
Frequency (GHz)

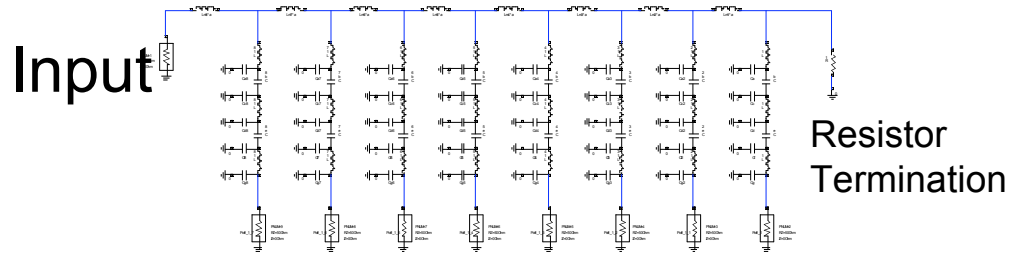
Frequency Response of the Slotline Antenna

# Broadband Slot Antenna Simulation

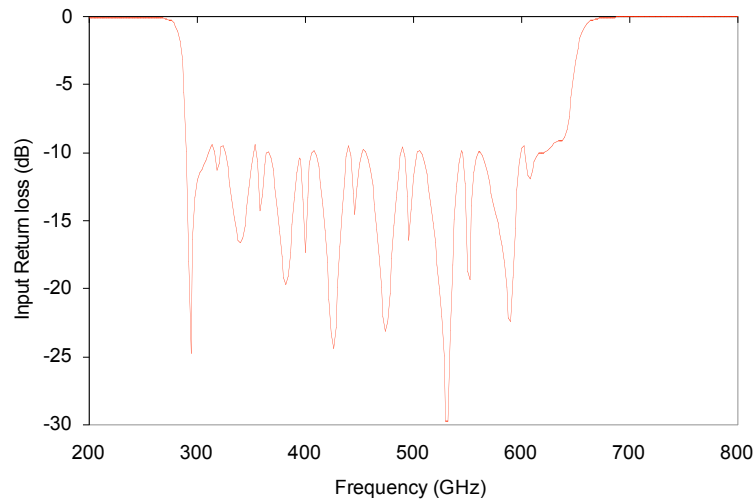


Slotline Antenna Gain Response at 650 GHz

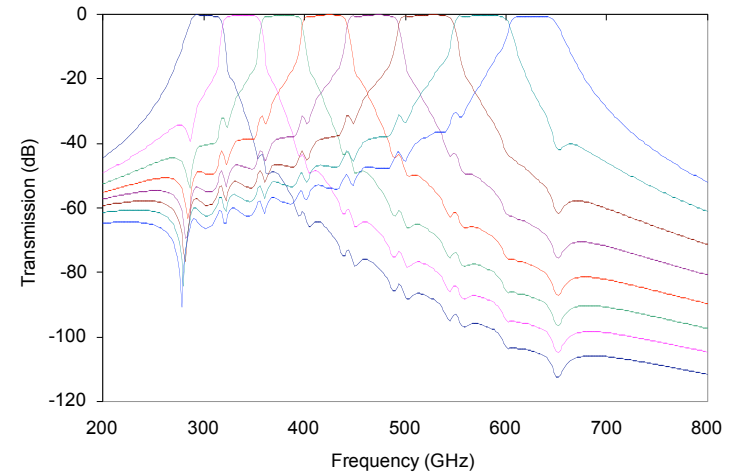
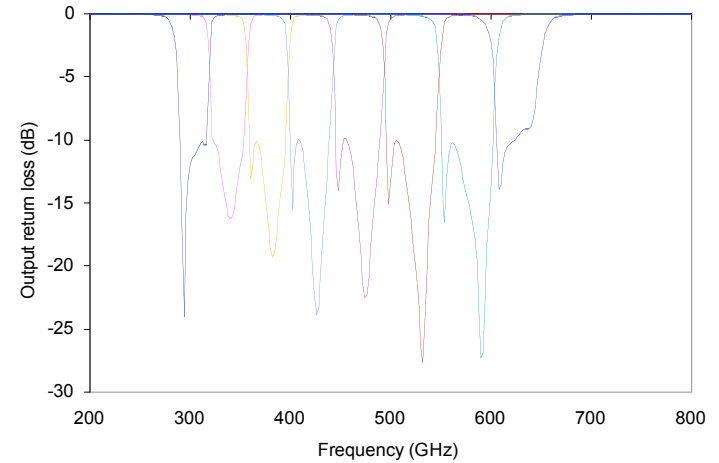
# Channelizing Filter



Eight output channels



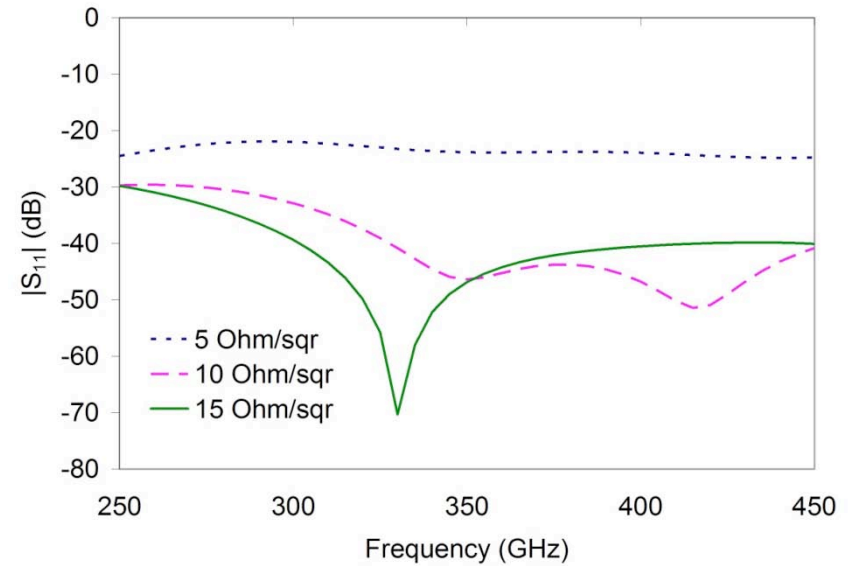
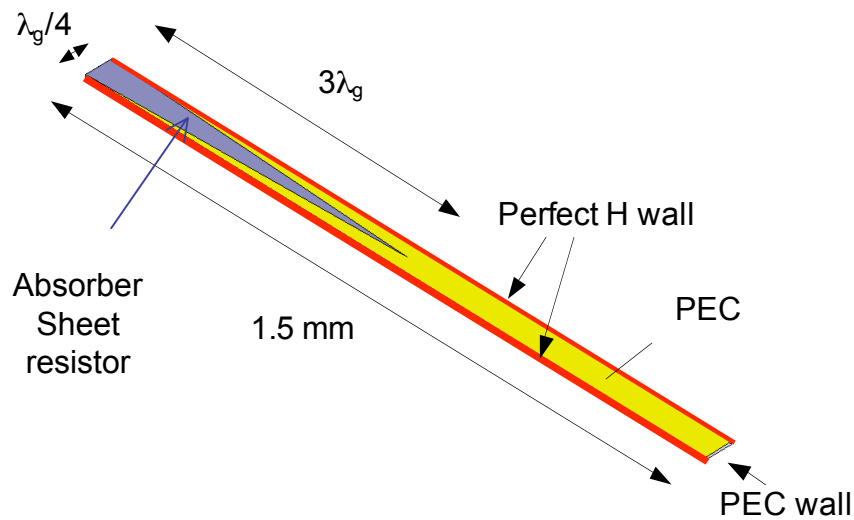
Input Return Loss



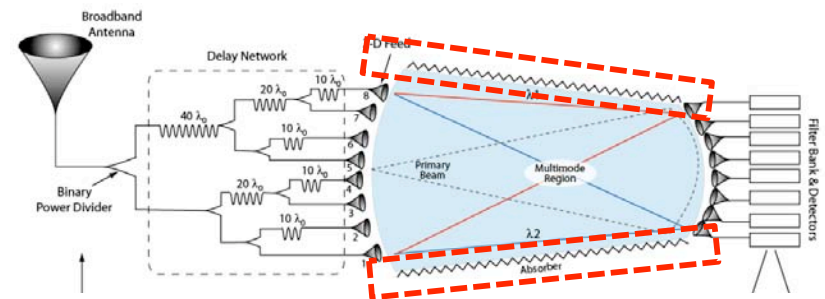
Filter Transmission & Return Loss

Interesting spectrophotometer by itself!

# Plane wave absorber

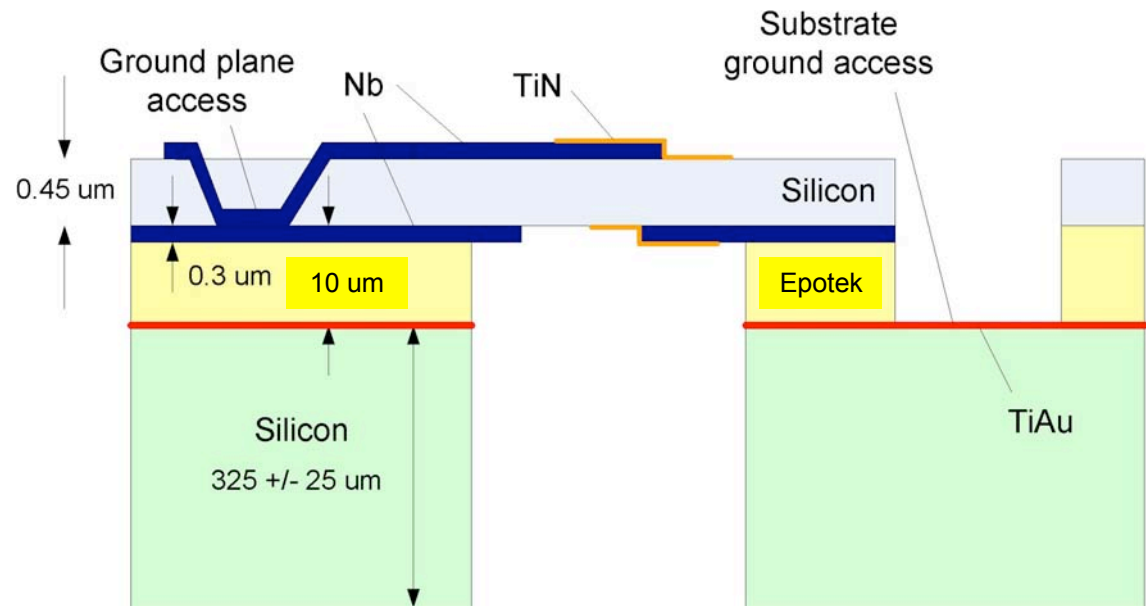


Unit cell model of the absorber on 0.45  $\mu\text{m}$  single-crystal Silicon substrate



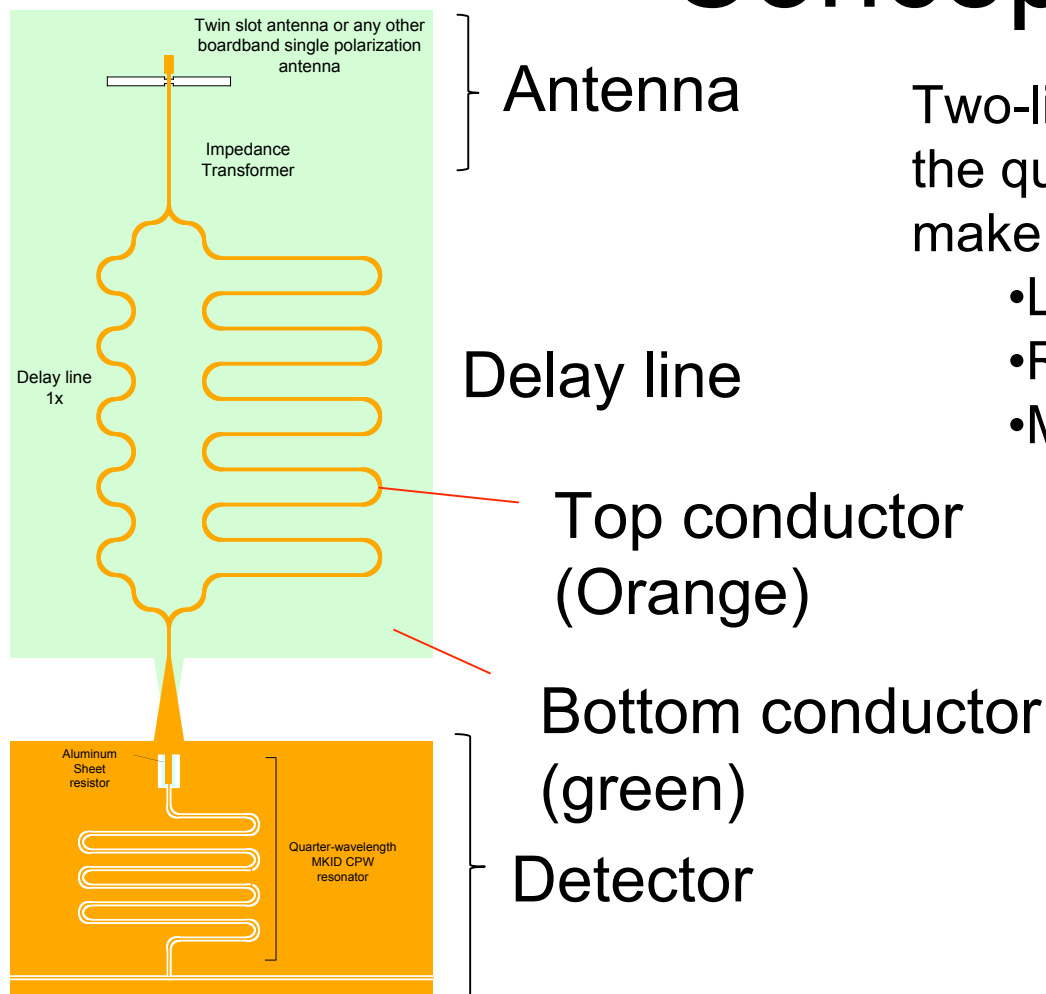
# Fabrication Stack up

Material	Thickness
TiN	55 nm
Nb	0.3 $\mu\text{m}$
Silicon	0.45 $\mu\text{m}$
Nb	0.3 $\mu\text{m}$
TiN	55 nm
Epotek	10 $\mu\text{m}$
Degenerately Doped Silicon	325 $\mu\text{m}$ +/- 25 $\mu\text{m}$





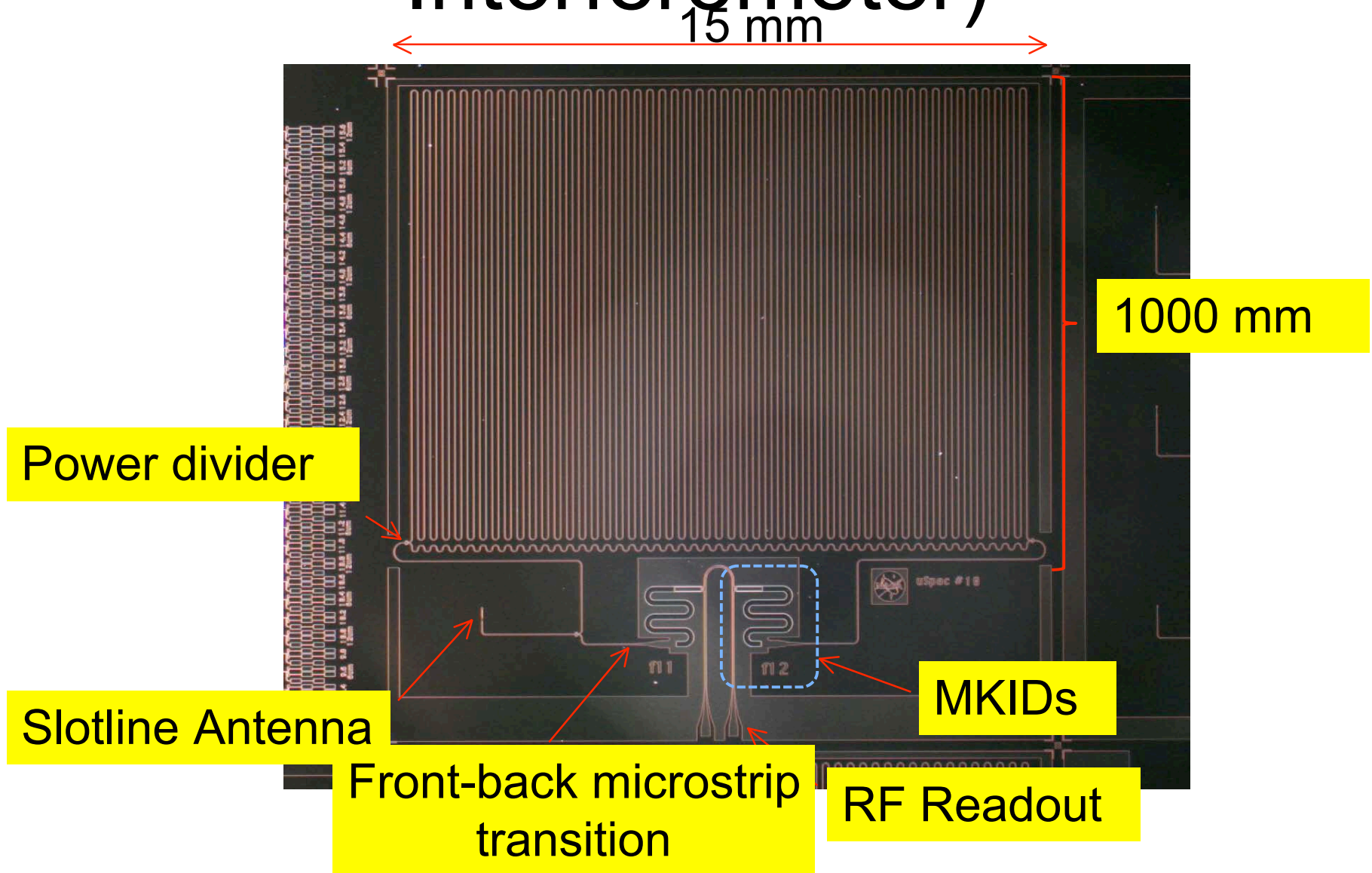
# Two-line Interferometer Concept



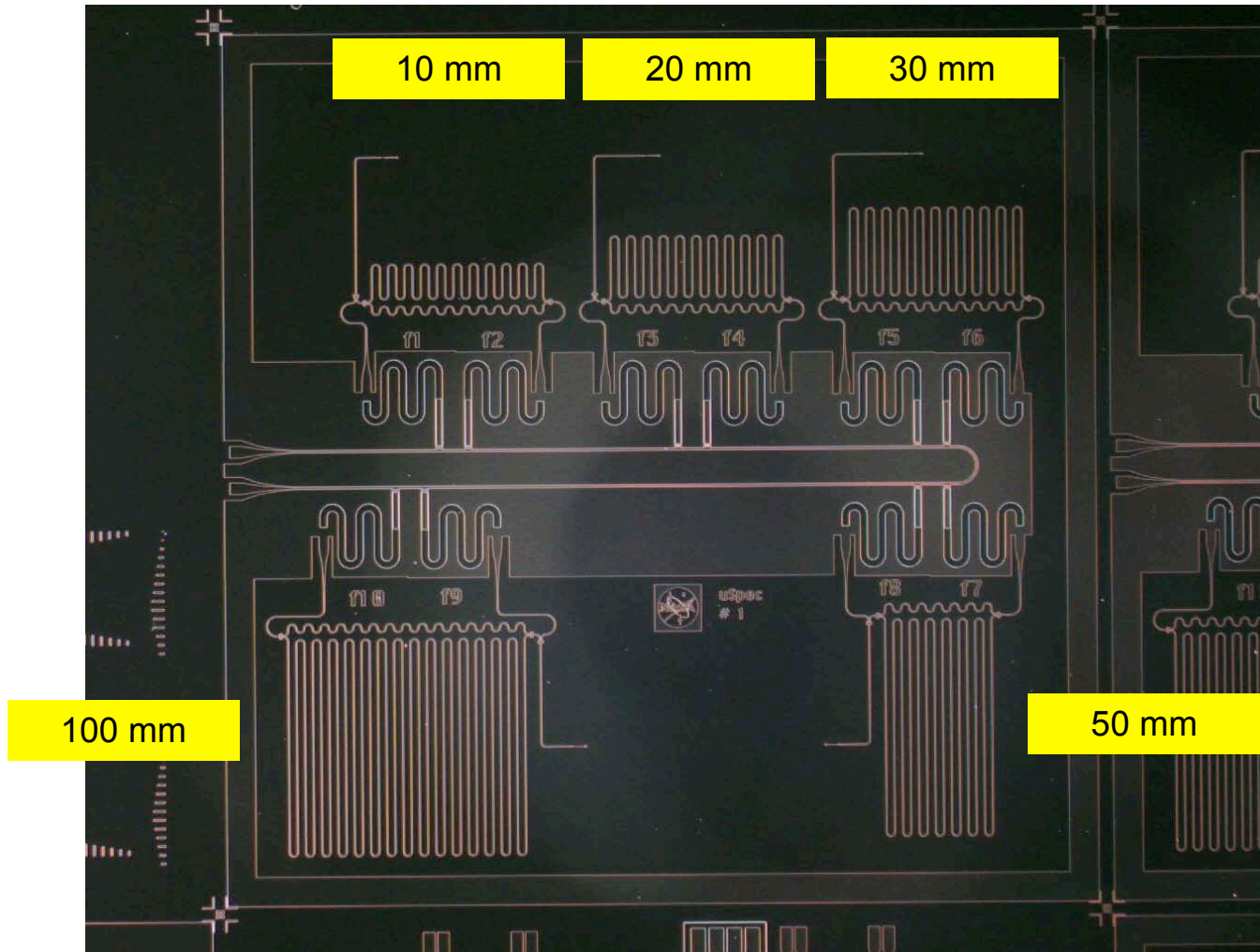
Two-line interferometer : determine the quality of the dielectric used to make the uSPEC

- Loss
- Resolving resolution
- MKID detection capability

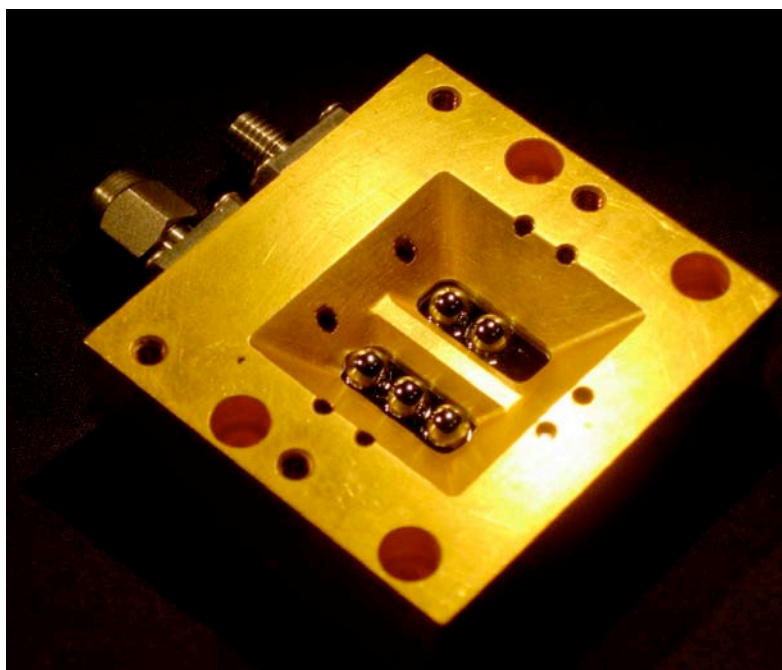
# Fabricated Devices (Two-Line Interferometer)



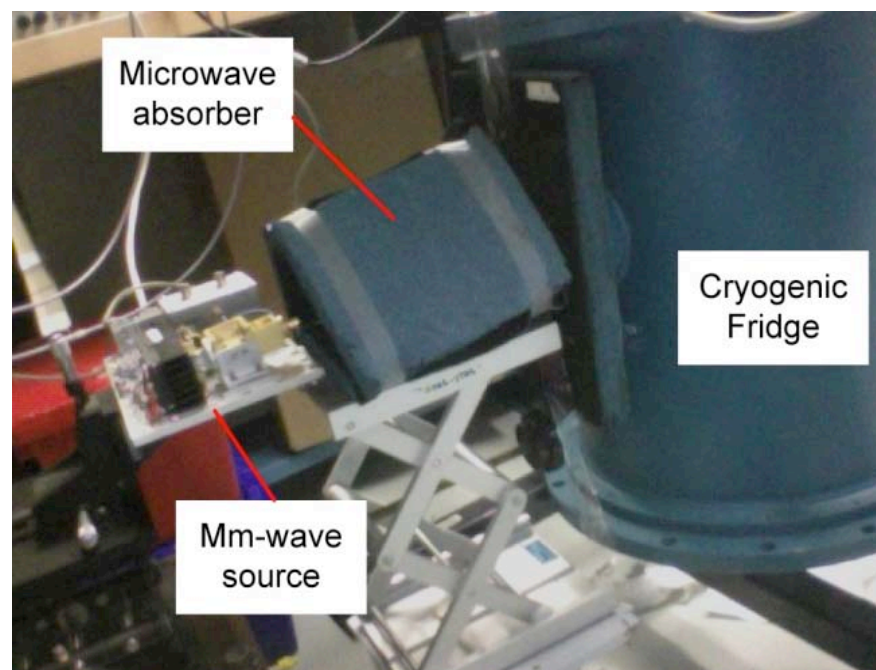
# Fabricated Two-line Interference Device



# Hardware Implementation



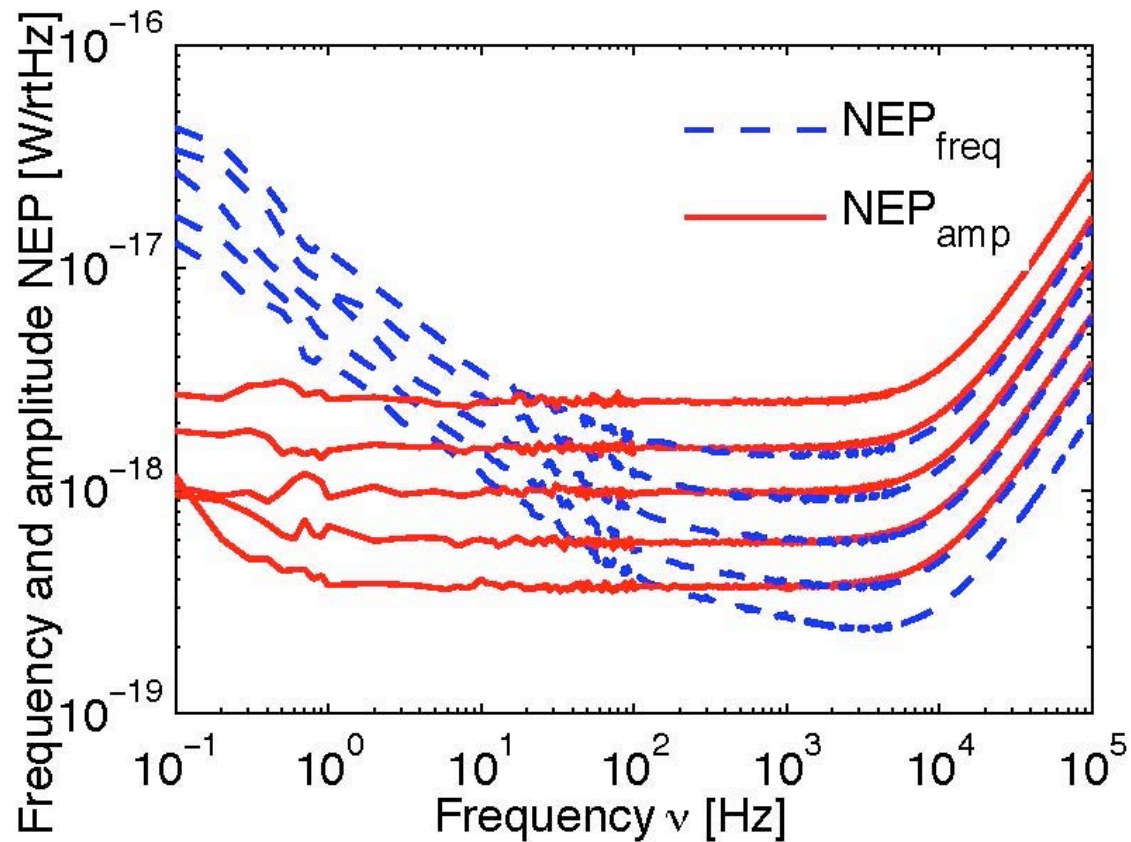
Two-line Interferometer Package



Two-line Interferometer Test Setup

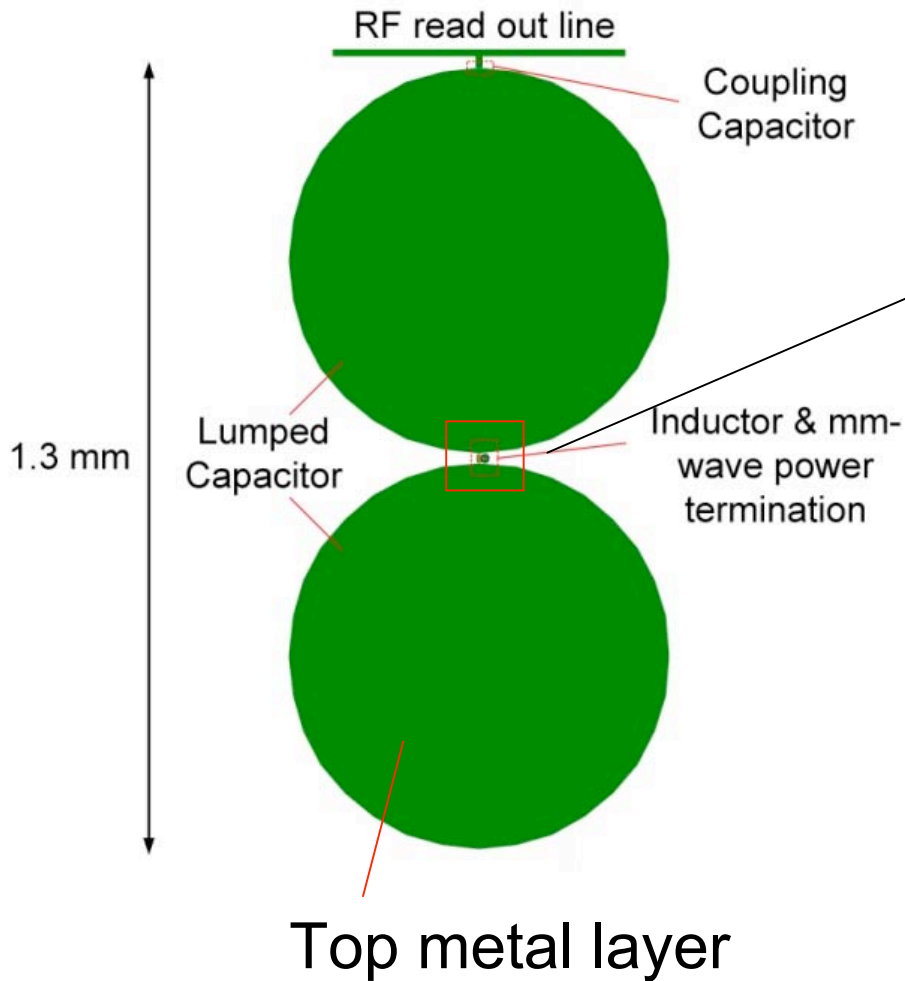


# Caltech/JPL MKID Noise



$$\tau = 200 \mu\text{s}, \quad NEP \sqrt{\tau} = 0.035 \text{ eV} \quad (35 \mu\text{m})$$

# Low NEP Detector Development

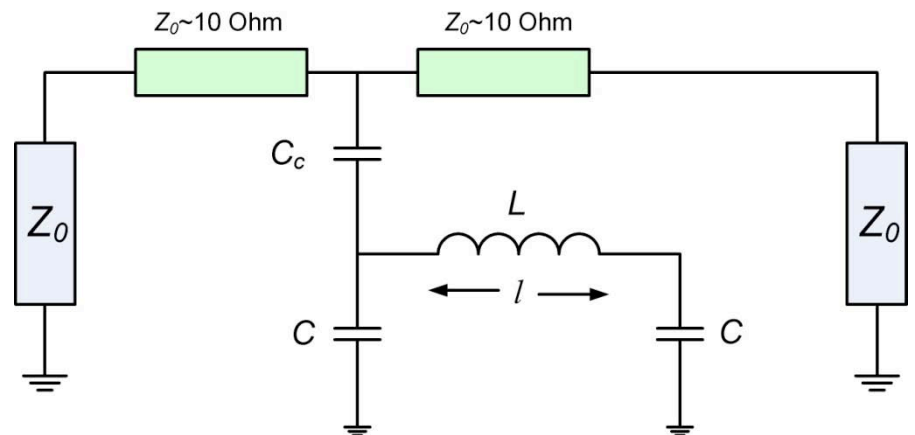


$$f_r = 1/(2\pi \sqrt{LC})$$

NEP  $\sim 2.5 \times 10^{-20} \text{ W}/\sqrt{\text{Hz}}$   
Should count mm photons!



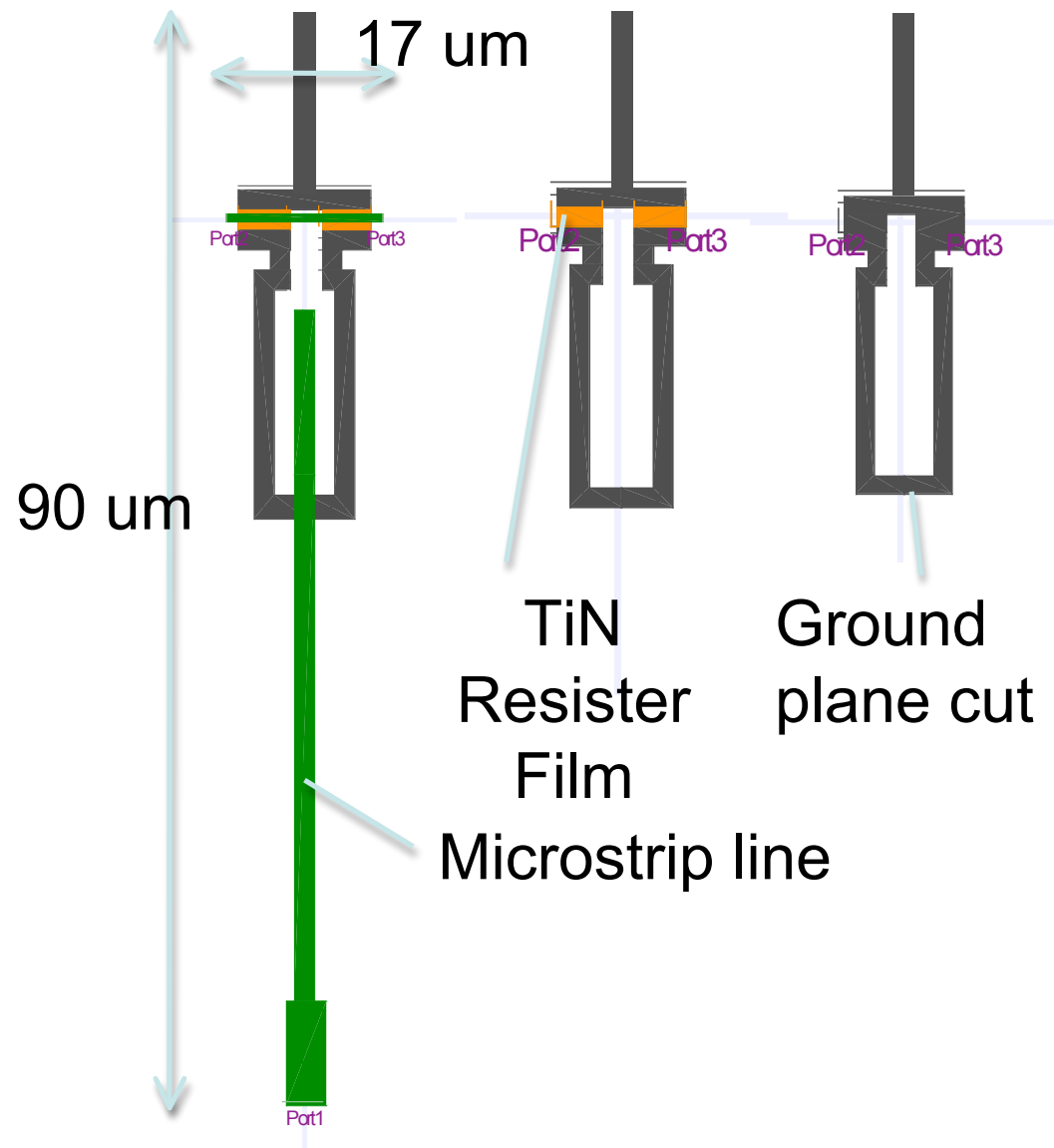
Infra-red absorber circuit



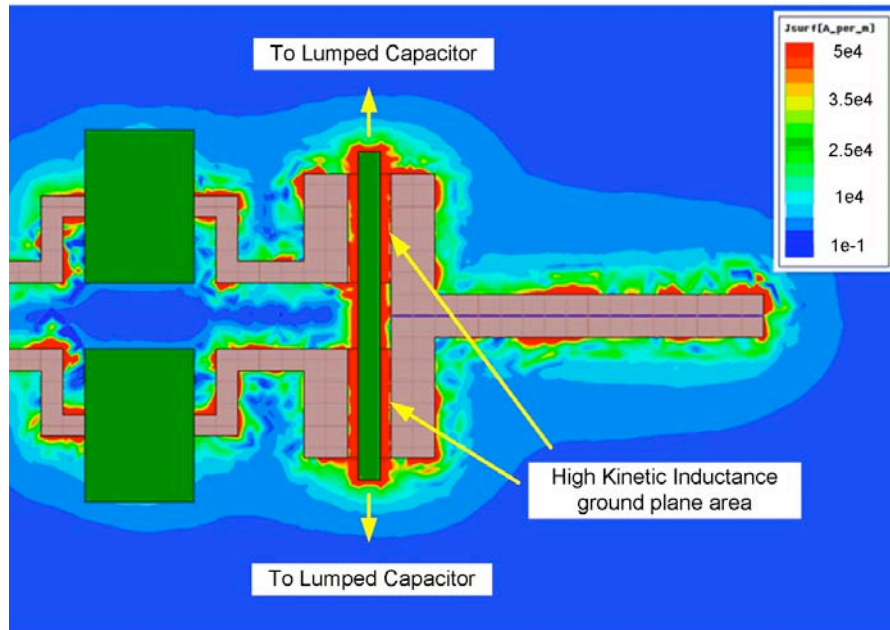
Equivalent Circuit Model

# Low Volume Detector Design

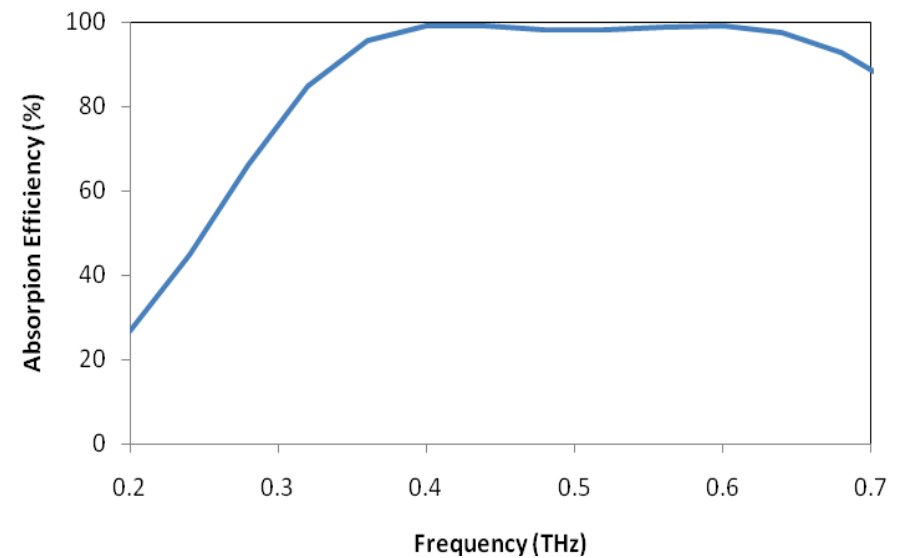
- CPW provide broadband termination for Ti-N sheet resistor
- Compact design with short resistor termination
- Cut-out slot prevent current from flowing around the resistor termination at RF frequencies
- Matching capacitor enhances the isolation level between the CPW input and the Resonator



# Detector Termination Frequency Response



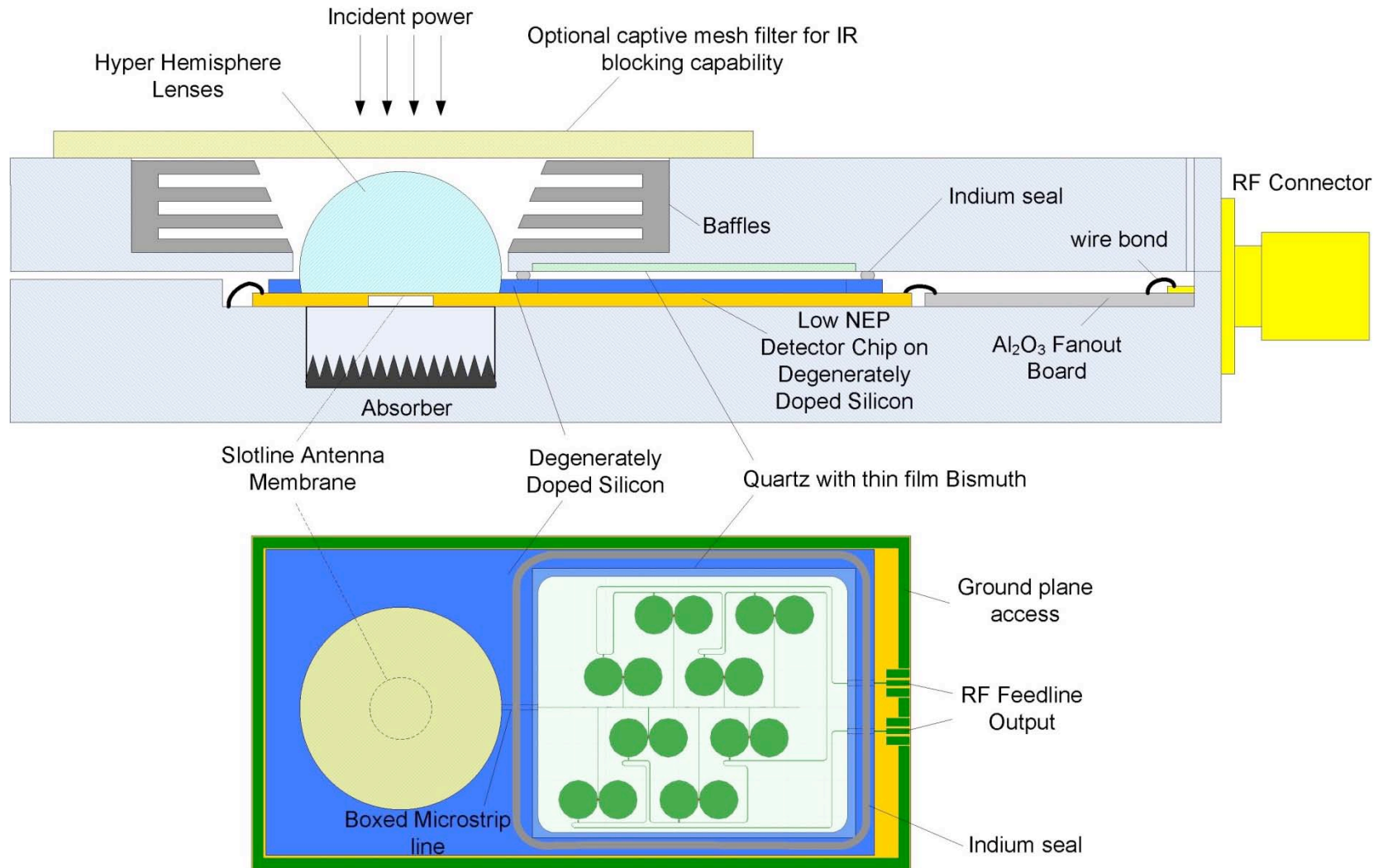
Simulated current density (A/m) of the ground plane with high kinetic inductance around the at 4 GHz



Frequency response of the detector termination

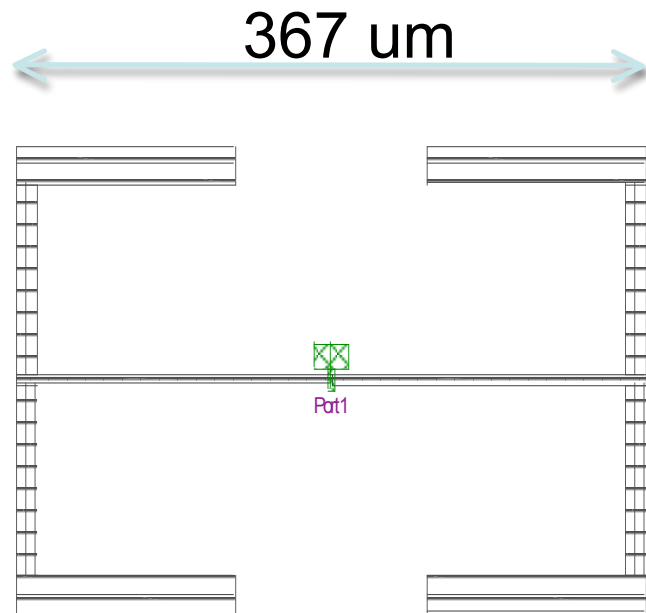


# Detector Packaging



Top view of the Low NEP Detector Chip

# Broadband Antenna

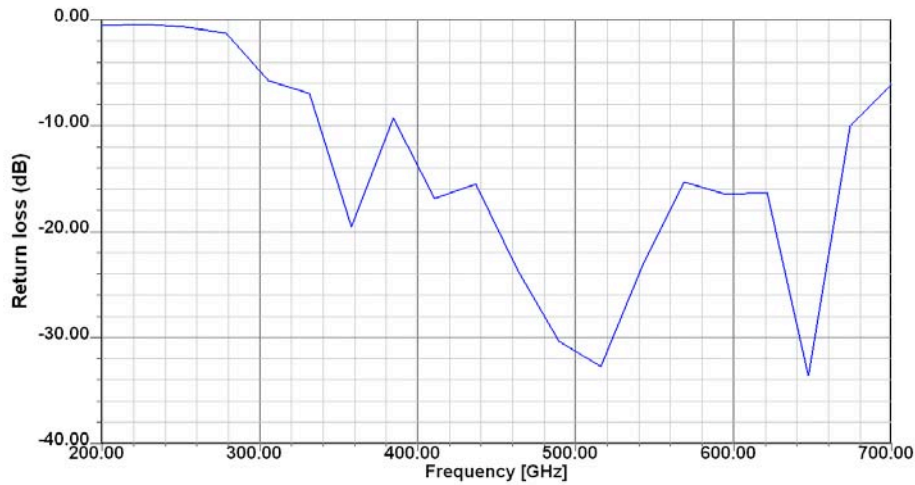


Physical layout of the Microstrip-feed Slotline Antenna



Slot antenna setup with hyper-hemisphere lens : Si sphere radius = 1 mm, Radiation sphere radius = 1.2mm

# Antenna Radiation Pattern and Frequency Responses



Antenna Return loss Response

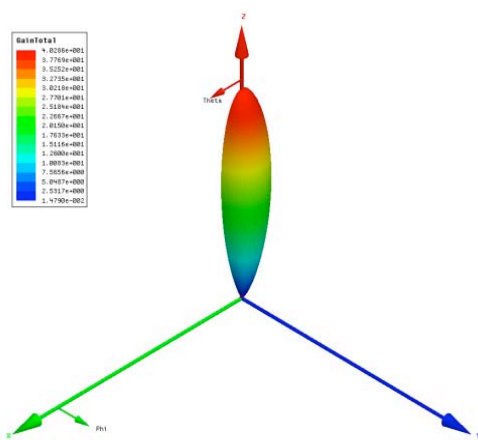
Antenna gain at 650 GHz

# Antenna Radiation Pattern

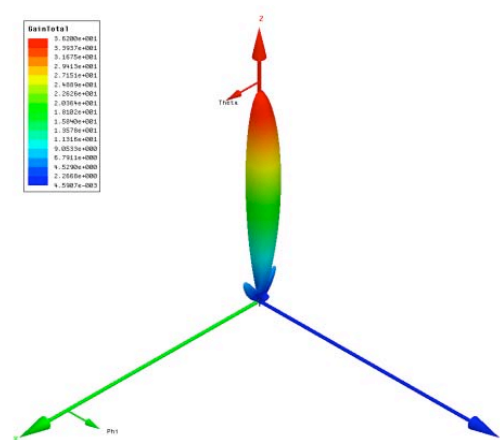
Antenna gain at 350 GHz - 3dB  
Beam width ~ 19 degree

Antenna gain at 500 GHz

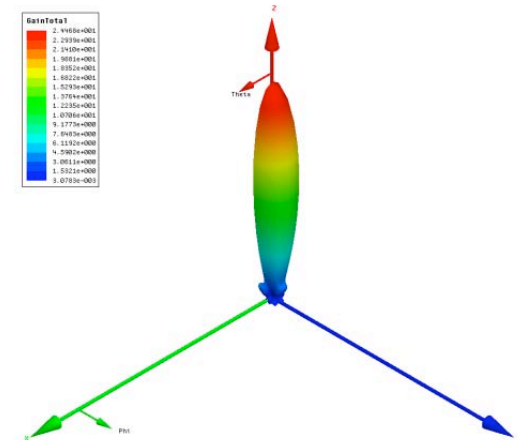
# Slot Antenna 3D Radiation Pattern



350 GHz



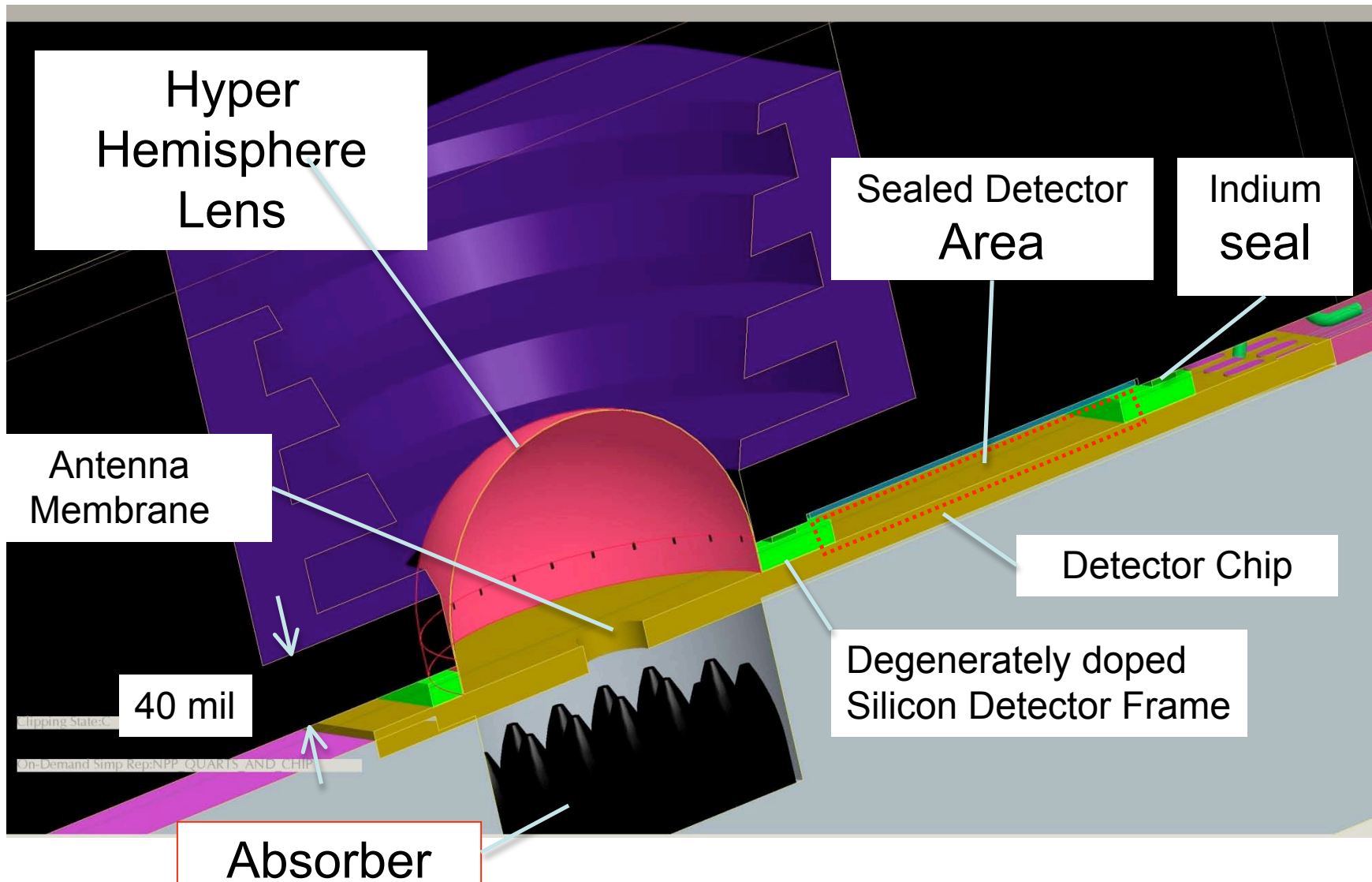
500 GHz



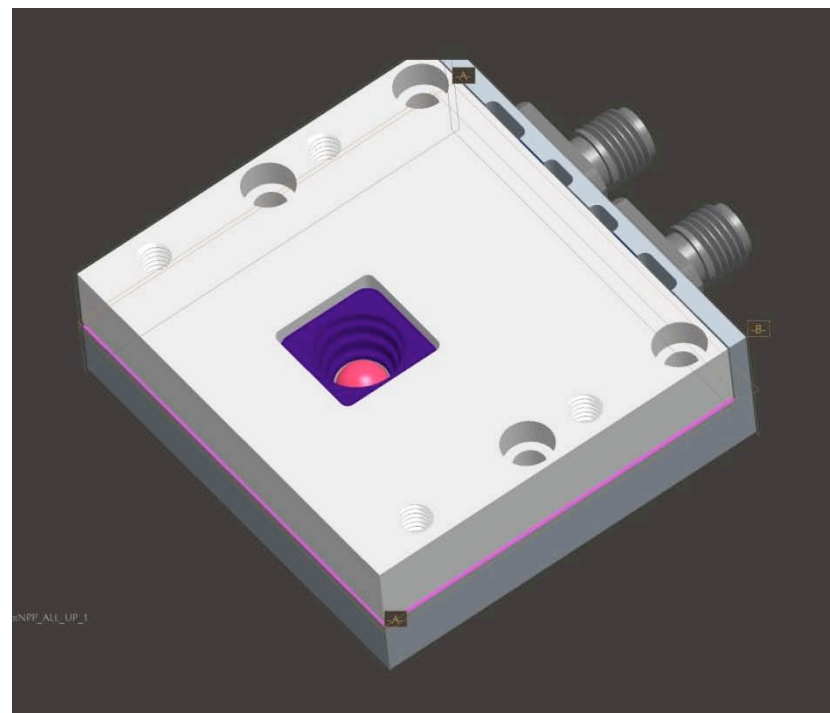
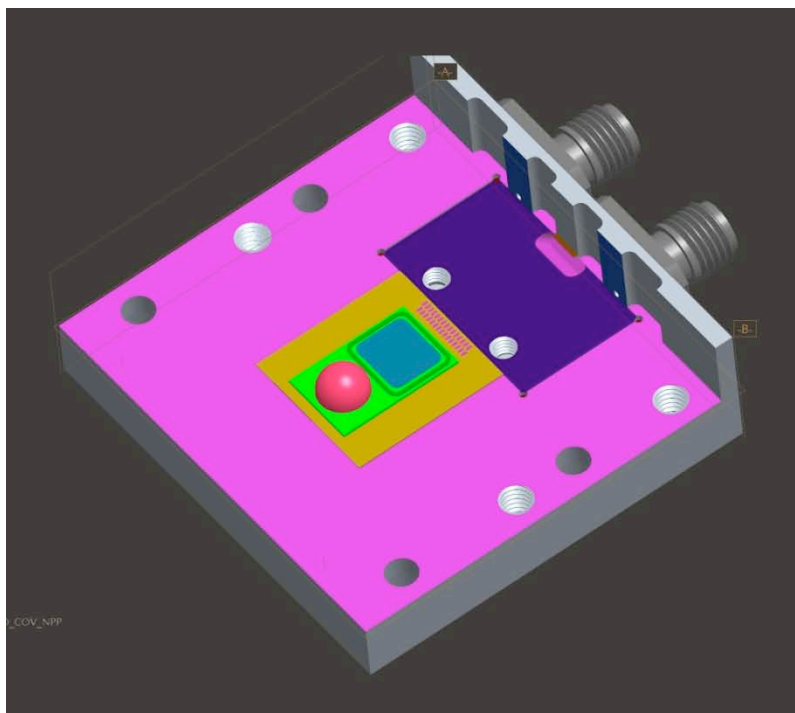
650 GHz

3D Radiation Pattern of the Low-NEP Slot antenna at 300, 500 and 650 GHz

# Low NEP Detector Optical Interface Area



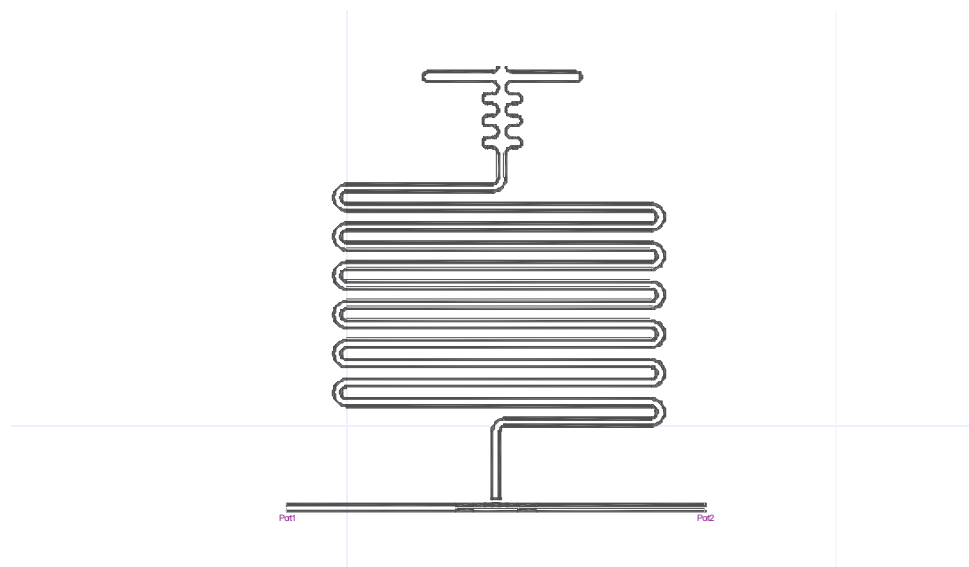
# 3D View of the detector package



Detector Assembly without cover Detector Assembly with cover

# Substrate Characterization

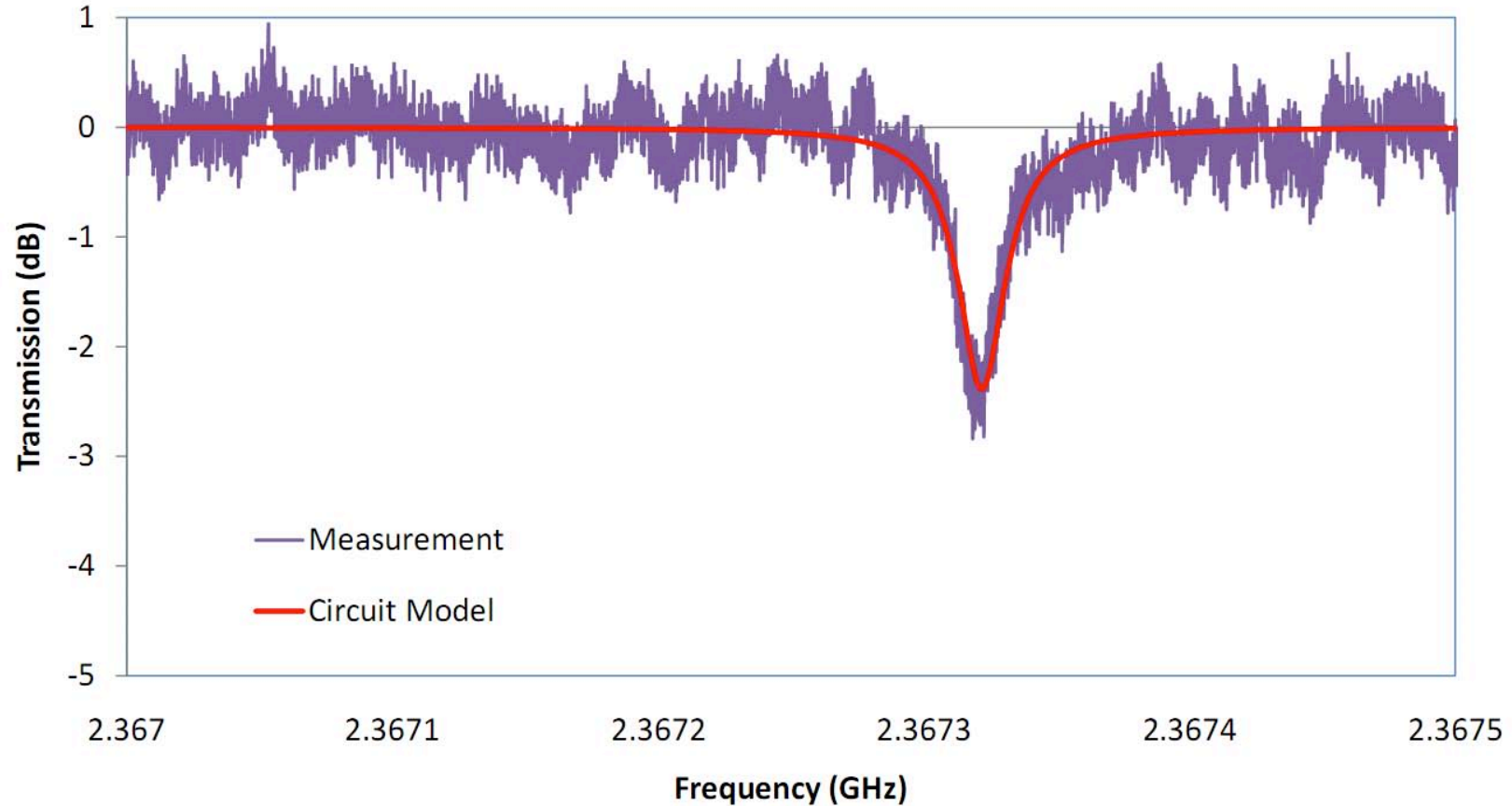
- TiN Resonator
- MoN Resonator



CPW resonator under investigation

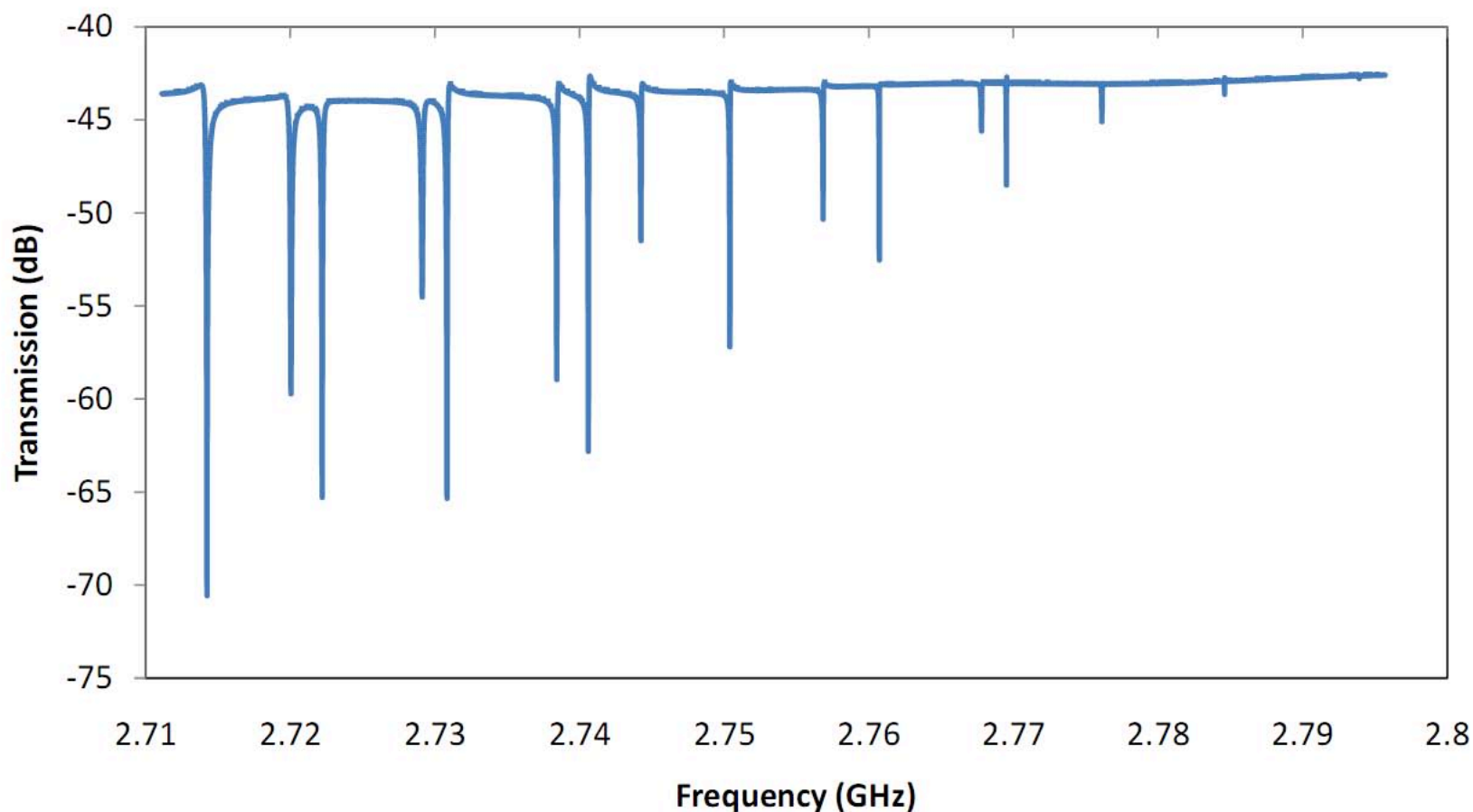


# TiN Measurement Results



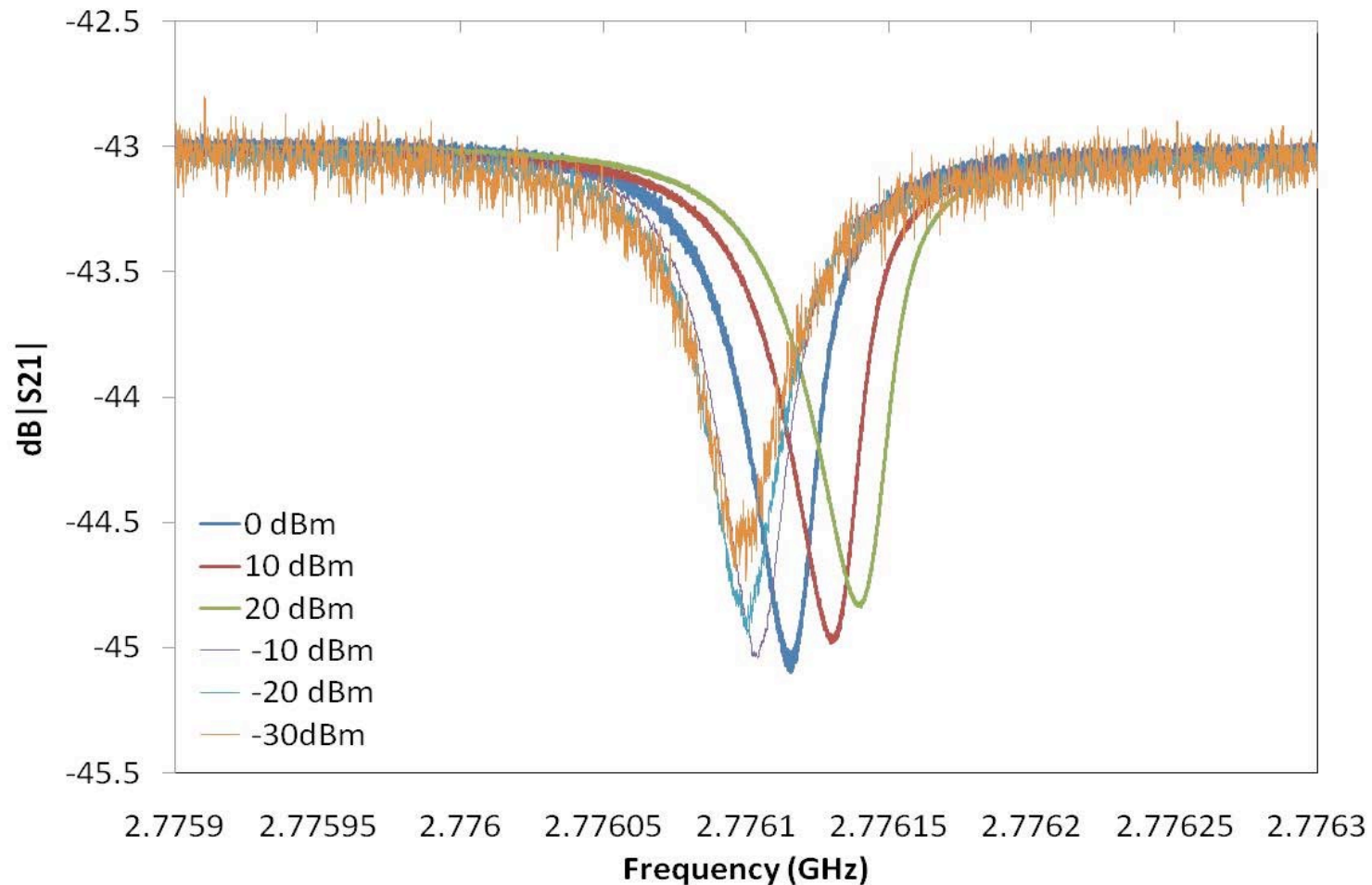
Measured and circuit model frequency response of the CPW resonator: Extracted Coupling  $Q = 394,553$   
Extracted Internal  $Q = 126,954$

# MoN Resonator Frequency Response at 0.4 K



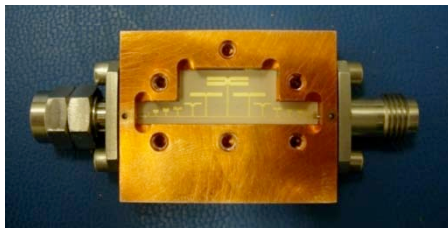
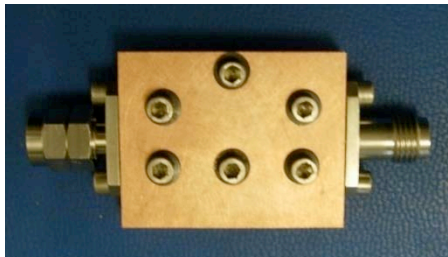
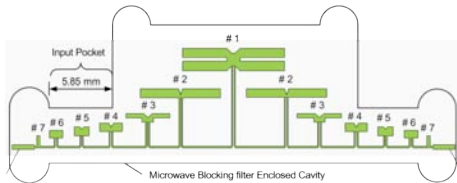
Frequency response of the MoN CPW resonators test structure containing 16 resonators  $Q_c$  ranges from  $10^4$  to  $10^8$ .

# Shift in resonator frequency due to input power level (-50 to -100 dBm)





# Thermal Blocking Filter: GHz...



Thermal Blocking Filter on ~125um Duroid

Measured DC parameters:

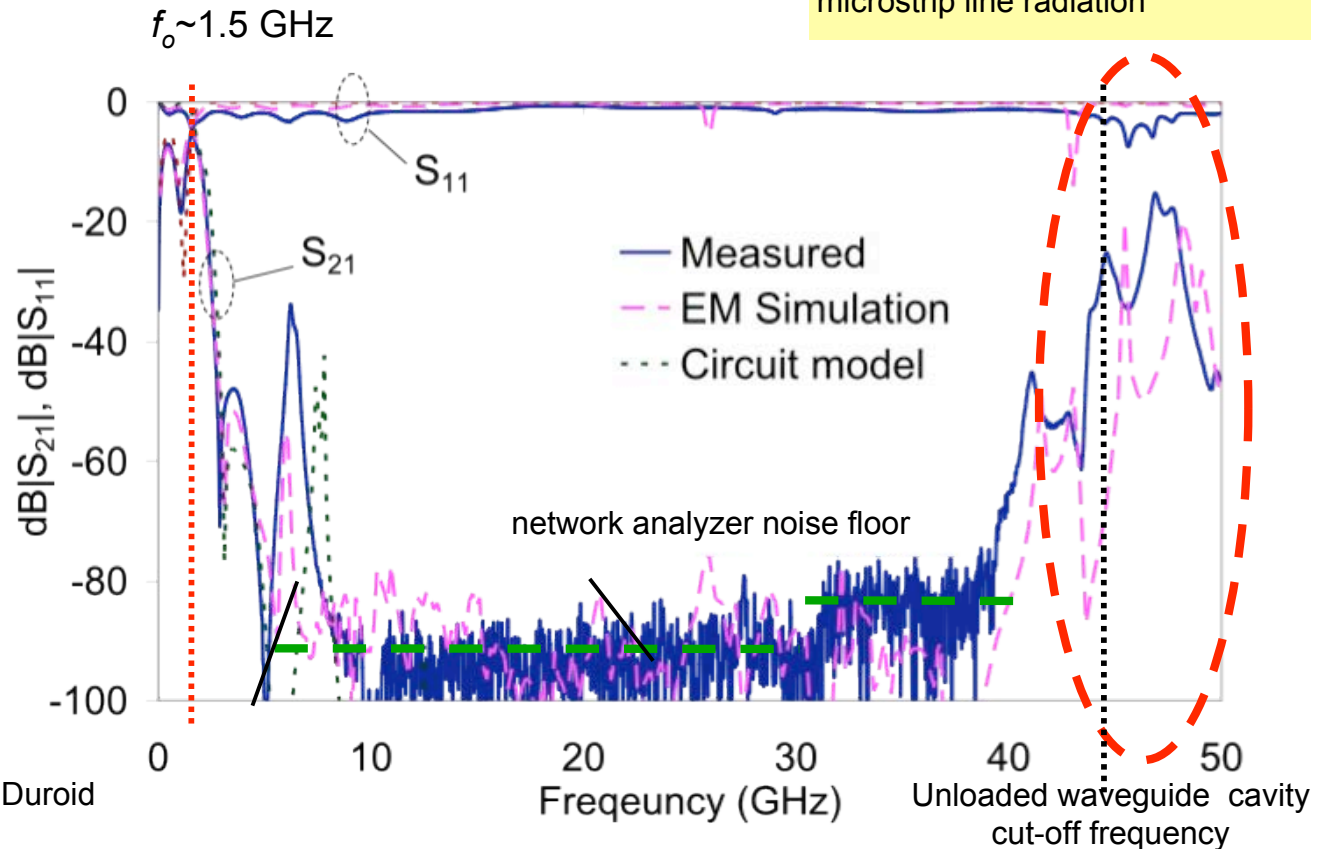
Capacitance ~ 22.4pF

Inductance ~ 49nH (@1MHz)

Series Resistance ~ 0.92ohm (@300K)

Series Resistance ~ 0.27ohm (@4K)

Waveguide cavity resonances & microstrip line radiation



REFERENCE: U-Yen, K. and Wollack, E.J., "Compact Planar Microwave Blocking Filter," 2008, 38th European Microwave Conference, Amsterdam, Netherlands, in press.



# $\mu$ -Spec: Features

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- Is the first fully integrated high performance spectrometer system
- Can couple to large two dimensional arrays of detectors in a very small volume
- Can operate up to 700-1200 GHz
  - Set by available superconductors
- Can provide  $R \sim 500$  by fabrication tolerances,  $> 1500$  by delay line trimming
- Can be mass produced
- Optics can be highly corrected to provide diffraction limited imaging of the spectrum



# Status

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- All basic elements have been produced
  - Nb transmission lines with single crystal Si dielectric show low loss
    - $Q_{\text{dielectric}} > 1000$  at 35 GHz
  - Tolerances are acceptable
    - R~500 possible by tolerance alone
  - No other complicated circuit elements
  - Relatively simple fabrication process
    - Needs only 3 metal layers



# Benefits of Integrated Optics

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- Compact
- Provide highly protected environment for photon counting detectors
  - Single mode in, power divided
  - Microstrip has low loss
  - Highly filtered interfaces
  - Can be almost completely boxed at operating temperature.



# Summary

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Integrated optics provide ideal environment for low-NEP photon counting detectors in the THz region

Provide practical technique for using large arrays of detectors for THz spectrometers

Enables very compact instruments; > 100 spectrometers, >  $10^5$  pixels

Instrument mass/volume/power dominated by electronics